Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.260 inches
Overall Diameter:
0.280 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
14.8 breakdown voltage, dc
Current Rating Per Characteristic:
65.00 milliamperes forward current, average peak
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
165.0 degrees celsius ambient air
Terminal Type And Quantity:
1 tab w/wire lead and 1 insulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0